



20V P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

| V _{(BR)DSS} | R _{DS(on)} Max | I _D Max @ T _A = 25°C (Note 4) |
|----------------------|---------------------------------|--|
| | 495mΩ @ V _{GS} = -4.5V | -0.59A |
| -20V | 690mΩ @ V _{GS} = -2.5V | -0.50A |
| | 960mΩ @ V _{GS} = -1.8V | -0.42A |

Description and Applications

This MOSFET has been designed to minimize the on-state resistance $(R_{DS(on)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Portable electronics

Features and Benefits

- Footprint of just 3mm² less than half the size of SOT23
- 0.8mm profile ideal for low profile applications
- Low Gate Threshold Voltage
- Fast Switching Speed
- ESD Protected Gate 3KV
- Totally Lead-Free & Fully RoHS compliant (Note 1)
- Halogen and Antimony Free. "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

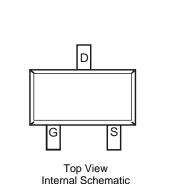
- Case: SOT523
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish ; Solderable per MIL-STD-202, Method 208
- Weight: 0.002 grams (approximate)

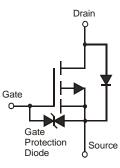




SOT523

Bottom View





Equivalent Circuit

Ordering Information (Note 3)

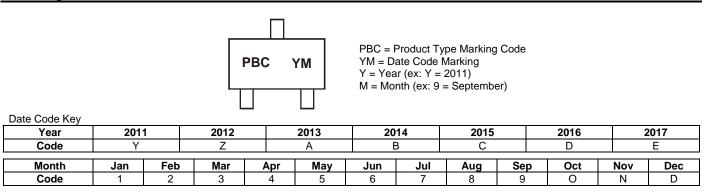
| Part Number | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|-------------|---------|--------------------|-----------------|-------------------|
| DMP21D0UT-7 | PBC | 7 | 8 | 3,000 |

Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. No purposely added lead. Halogen and Antimony free.

2. Diodes Inc's "Green" policy can be found on our website at http://www.diodes.com.

3. For packaging details, go to our website at http://www.diodes.com.

Marking Information





Notes:



DMP21D0UT

Maximum Ratings @T_A = 25°C unless otherwise specified

| Characteristic | | Symbol | Value | Unit V | |
|---|-----------------|--|------------------|-------------------------|-----|
| Drain-Source Voltage Gate-Source Voltage | | | V _{DSS} | | -20 |
| | | | V _{GSS} | ±8 | V |
| Continuous Drain Current | Steady State | $T_A = 25^{\circ}C$ (Note 4) $T_A = 85^{\circ}C$ (Note 4) $T_A = 25^{\circ}C$ (Note 5) | ID | -0.59 -0.42 -0.65 | А |
| Pulsed Drain Current (Note 6 |) | | IDM | -5.0 | А |

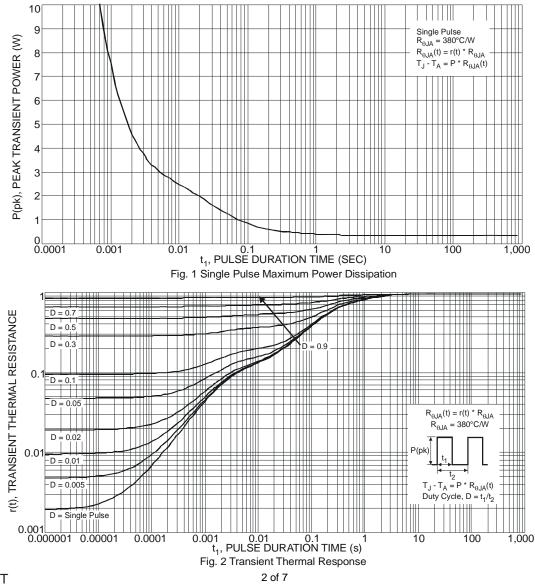
Thermal Characteristics @T_A = 25°C unless otherwise specified

| Characteristic | Symbol | Value | Unit |
|--|-----------------------------------|-------------|------|
| Power Dissipation (Note 4) | PD | 0.24 | W |
| Power Dissipation (Note 5) | PD | 0.33 | W |
| Thermal Resistance, Junction to Ambient (Note 4) | R _{0JA} | 525 | °C/W |
| Thermal Resistance, Junction to Ambient (Note 5) | R _{0JA} | 383 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

4. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout

5. Device mounted on 25mm X 25mm FR-4 PCB with high coverage of 2oz copper

6. Device mounted on minimum recommended pad layout test board, 10µs pulse duty cycle = 1%.



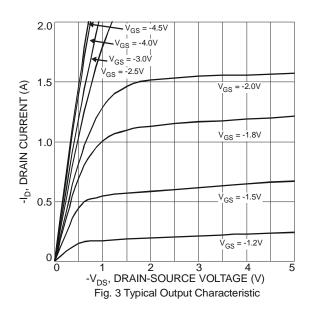
DMP21D0UT Datasheet Number: DS35297 Rev. 2 - 2

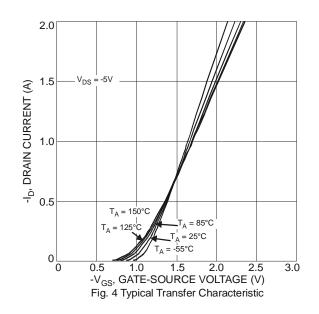




| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|---|----------------------|-----|------|------|------|---|--|
| OFF CHARACTERISTICS (Note 7) | | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | -20 | - | - | V | $V_{GS} = 0V, I_D = -250 \mu A$ | |
| Zero Gate Voltage Drain Current T _J = 25°C | I _{DSS} | - | - | -1 | μA | $V_{DS} = -20V, V_{GS} = 0V$ | |
| Gate-Source Leakage | IGSS | - | - | ±10 | μA | $V_{GS} = \pm 8V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 7) | | | - | - | | | |
| Gate Threshold Voltage | V _{GS(th)} | - | -0.7 | - | V | $V_{DS} = V_{GS}$, $I_D = -250 \mu A$ | |
| | | - | - | 495 | mΩ | $V_{GS} = -4.5V, I_D = -400mA$ | |
| Static Drain-Source On-Resistance | R _{DS} (ON) | | | 690 | | $V_{GS} = -2.5V, I_D = -300mA$ | |
| | | | | 960 | | $V_{GS} = -1.8V, I_D = -100mA$ | |
| Forward Transfer Admittance | Y _{fs} | 50 | - | - | mS | $V_{DS} = -3V, I_{D} = -300mA$ | |
| Diode Forward Voltage | V _{SD} | - | - | -1.2 | V | $V_{GS} = 0V, I_{S} = -300mA$ | |
| DYNAMIC CHARACTERISTICS | | | | | | | |
| Input Capacitance | Ciss | - | 76.5 | - | pF | − V _{DS} = -10V, V _{GS} = 0V, − f = 1.0MHz | |
| Output Capacitance | Coss | - | 13.7 | - | pF | | |
| Reverse Transfer Capacitance | C _{rss} | - | 10.7 | - | pF | | |
| Gate Resistance | Rg | - | 195 | - | Ω | $V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$ | |
| Total Gate Charge | Qg | | 1.5 | - | nC | $V_{GS} = -8V, V_{DS} = -15V, I_D = -14$ | |
| Total Gate Charge | Qg | - | 1.0 | - | nC | | |
| Gate-Source Charge | Q _{gs} | - | 0.2 | - | nC | $-V_{GS} = -4.5V, V_{DS} = -15V,$ $-I_{D} = -1A$ | |
| Gate-Drain Charge | Q _{gd} | - | 0.3 | - | nC | | |
| Turn-On Delay Time | t _{D(on)} | - | 7.1 | - | ns | | |
| Turn-On Rise Time | tr | - | 8.0 | - | ns | V _{DS} = -10V, -I _D = 1A | |
| Turn-Off Delay Time | t _{D(off)} | - | 31.7 | - | ns | $V_{\rm GS} = -4.5 \text{V}, \text{ R}_{\rm G} = 6 \Omega$ | |
| Turn-Off Fall Time | t _f | - | 18.5 | - | ns | | |

7. Short duration pulse test used to minimize self-heating effect. Notes:







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 $_{\Lambda} = 150^{\circ}C$

_A = 125°C

T_A = 85°C

 $T_A = 25^{\circ}C$

T_A = -55°C

0.8

V_{GS} = -5.0V $I_{D} = -500 \text{mA}$

25

50

0.8

75

T_A = 25°C

1.0

1.2

-I_D, DRAIN CURRENT (A)

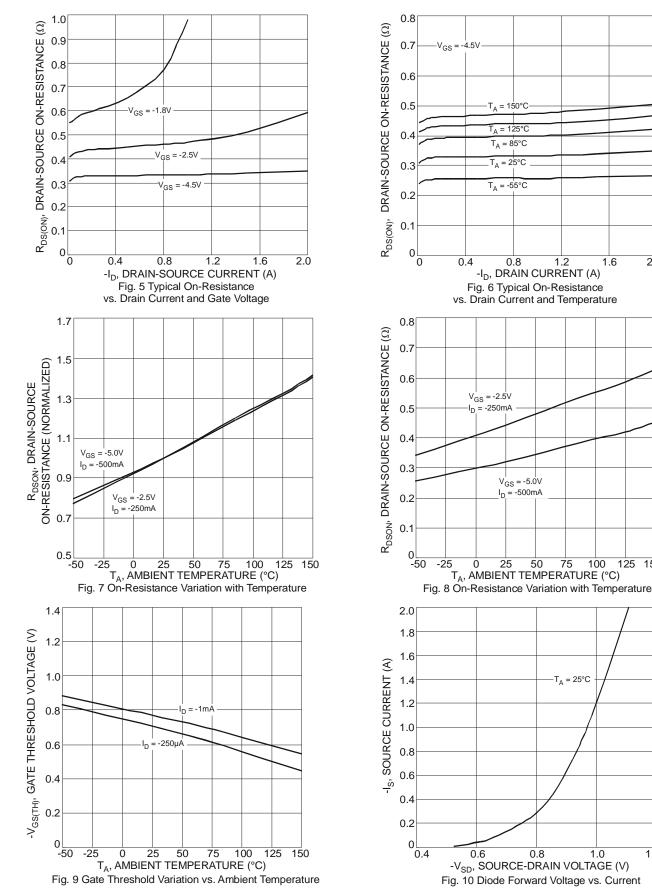
1.6

100 125 150

2.0



DMP21D0UT

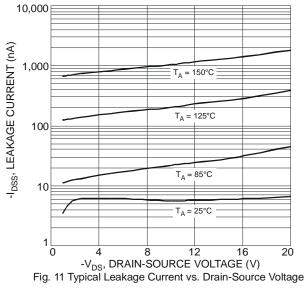


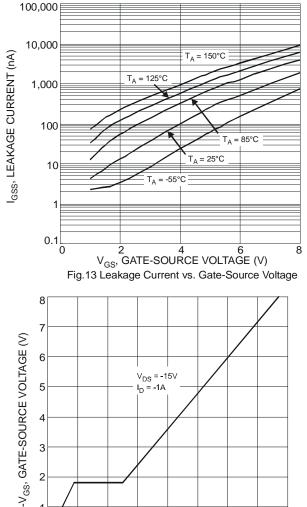
1.2











0.6

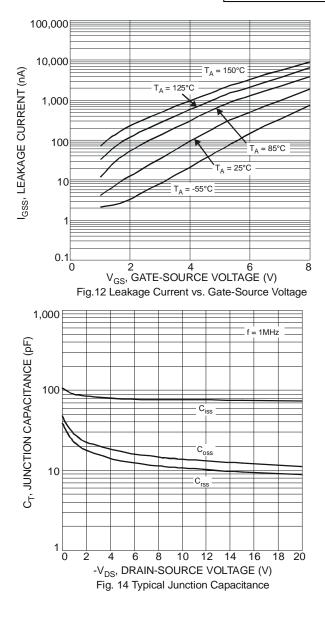
0.4

0.8

Q_g, TOTAL GATE CHARGE (nC) Fig. 15 Gate-Charge Characteristics

1.0

1.2



0.2

1

0 0

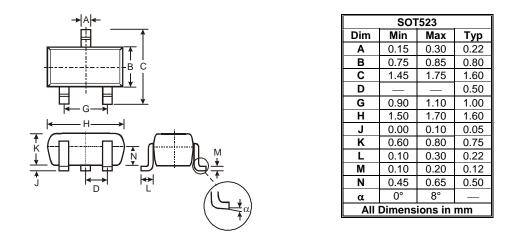
1.6

1.4

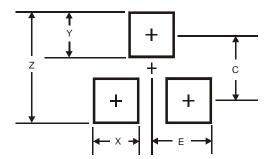




Package Outline Dimensions



Suggested Pad Layout



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 1.8 |
| Х | 0.4 |
| Y | 0.51 |
| С | 1.3 |
| E | 0.7 |





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